# 10/581674 AP3 Rec'd PCT/PTO 05 JUN 2004

#### **Application Data Sheet**

### **Application Information**

Application number::

Filing Date::

Application Type::

Subject Matter:: '

Title ::

Regular

Utility

METHOD FOR

MANUFACTURING THIN

FILM INTEGRATED CIRCUIT

DEVICE, NONCONTACT

THIN FILM INTEGRATED

**CIRCUIT DEVICE AND** 

METHOD FOR

MANUFACTURING THE

SAME, AND IDTAG AND

COIN INCLUDING THE

NONCONTACT THIN FILM

INTEGRATED CIRCUIT

DEVICE

Attorney Docket Number::

0756-7719

**Total Drawing Sheets::** 

23

Small Entity?::

No

## Applicant Information

**Applicant Authority Type:**:

Inventor

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Page #1

Initial 06/05/2006

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#### **Domestic Priority Information**

Application ::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	National Stage	PCT/JP2004/018978	12/14/2004

#### Foreign Priority Information

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2003-417317	12/15/2003	Yes

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